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TPS3606-33DGS

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Datasheet of TPS3606-33DGS - IC BATT BACKUP SUPERVISR 10-MSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

TPS3606-33

BATTERY-BACKUP SUPERVISOR FOR LOW-POWER PROCESSORS

SLVS335C - DECEMBER 2000 - REVISED JANUARY 2007

features

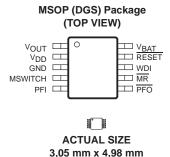
- Supply Current of 40 µA (Max)
- **Precision 3.3-V Supply Voltage Monitor** Other Voltage Options on Request
- Watchdog Timer With 800-ms Time-Out
- Backup-Battery Voltage Can Exceed VDD
- **Power-On Reset Generator With Fixed** 100-ms Reset Delay Time
- Voltage Monitor for Power-Fail or **Low-Battery Monitoring**
- Manual Switchover to Battery-Backup Mode
- **Manual Reset**
- **Battery Freshness Seal**
- 10-Pin MSOP Package
- Temperature Range . . . -40°C to 85°C

description

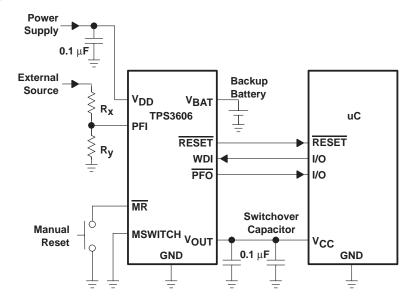
The TPS3606-33 supervisory circuit monitors and controls the processor activity. In case of powerfail or brownout conditions, the backup-battery switchover function of the TPS3606-33 allows a low-power processor and its peripherals to run from the installed backup battery without asserting a reset beforehand.

typical applications

- **Fax Machines**
- **Set-Top Boxes**
- **Advanced Voice Mail Systems**
- **Portable Battery Powered Equipment**
- **Computer Equipment**
- **Advanced Modems**
- **Automotive Systems**
- **Portable Long-Time Monitoring Equipment**
- Point-of-Sale Equipment



typical operating circuit





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description (continued)

During power on, \overline{RESET} is asserted when the supply voltage (V_{DD} or V_{BAT}) becomes higher than 1.1 V. Thereafter, the supply voltage supervisor monitors V_{OUT} and keeps the \overline{RESET} output active as long as V_{OUT} remains below the threshold voltage (V_{IT}). An internal timer delays the return of the output to the inactive state (high) to ensure proper system reset. The delay time starts after V_{OUT} has risen above V_{IT}. When the supply voltage drops below V_{IT}, the output becomes active (low) again.

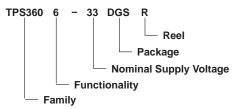
The TPS3606-33 is available in a 10-pin MSOP package and is characterized for operation over a temperature range of –40°C to 85°C.

PACKAGE INFORMATION

TA	DEVICE NAME	MARKING
-40°C to 85°C	TPS3606-33DGSR [†]	AKE

[†] The DGSR passive indicates tape and reel of 2500 parts.

ordering information application specific versions (see Note)



DEVICE NAME	NOMINAL VOLTAGE [‡] , V _{NOM}
TPS3606-33 DGS	3.3 V

[‡] For other threshold voltages, contact the local TI sales office for availability and lead-time.

FUNCTION TABLES TPS3606

V _{DD} > V _{SW}	V _{OUT} > V _{IT}	V _{DD} > V _{BAT}	V _{OUT}	RESET
0	0	0	VBAT	0
0	0	1	V_{DD}	0
0	1	0	V_{BAT}	1
0	1	1	V_{DD}	1
1	1	0	V_{DD}	1
1	1	1	V_{DD}	1

PFI > V _{PFI}	PFO
0	0
1	1

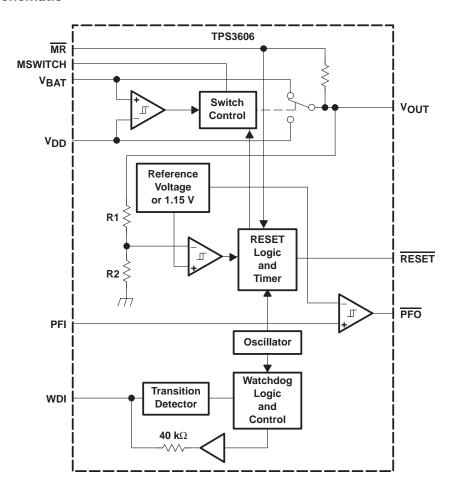
CONDITION.: V_{OUT} > V_{DD}(min)





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functional schematic

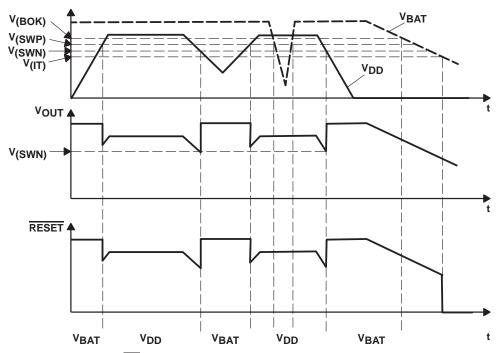






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timing diagram



NOTES: A. MSWITCH = 0, $\overline{MR} = 1$

Terminal Functions

TERMIN	AL	1/0	DECODINE	
NAME	NO.	1/0	DESCRIPTION	
GND	3	- 1	Ground	
MR	7	- 1	Manual reset input	
MSWITCH	4	- 1	Manual switch to force device into battery-backup mode	
PFI	5	- 1	Power-fail comparator input	
PFO	6	0	Power-fail comparator output	
RESET	9	0	Active-low reset output	
VBAT	10	I	Backup-battery input	
V_{DD}	2	I	Input supply voltage	
VOUT	1	0	Supply output	
WDI	8	1	Watchdog timer input	



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detailed description

battery freshness seal

The battery freshness seal of the TPS3606 family disconnects the backup battery from the internal circuitry until it is needed. This ensures that the backup battery connected to V_{BAT} is fresh when the final product is put to use. The following steps explain how to enable the freshness seal mode:

- Connect V_{BAT} (V_{BAT} > V_{BAT(min)})
- 2. Ground PFO
- 3. Connect PFI to V_{DD} or PFI > V_(PFI)
- 4. Connect V_{DD} to power supply (V_{DD} > V_{IT})
- Ground MR
- Power down V_{DD}
- 7. The freshness seal mode is entered and pins PFO and MR can be disconnected.

The battery freshness seal mode is disabled by the positive-going edge of RESET when V_{DD} is applied.

power-fail comparator (PFI and PFO)

An additional comparator is provided to monitor voltages other than the nominal supply voltage. The power-fail input (PFI) is compared with an internal voltage reference of 1.15 V. If the input voltage falls below the power-fail threshold (V_(PFI)) of 1.15 V typical, the power-fail output (PFO) goes low. If it goes above V_(PFI) plus about 12-mV hysteresis, the output returns to high. By connecting two external resistors, it is possible to supervise any voltages above $V_{(PFI)}$. The sum of both resistors should be about 1 M Ω , to minimize power consumption and also to ensure that the current in the PFI pin can be neglected compared with the current through the resistor network. The tolerance of the external resistors should be not more than 1% to ensure minimal variation of sensed voltage.

If the power-fail comparator is unused, connect PFI to ground and leave PFO unconnected.

backup-battery switchover

In the event of a brownout or power failure, it may be necessary to keep a processor running. If a backup battery is installed at V_{BAT}, the devices automatically connect the processor to backup power when V_{DD} fails. In order to allow the backup battery (e.g., a 3.6-V lithium cell) to have a higher voltage than V_{DD}, this family of supervisors does not connect V_{BAT} to V_{OUT} when V_{BAT} is greater than V_{DD} . V_{BAT} only connects to V_{OUT} (through a 2- Ω switch) when V_{OUT} falls below $V_{(SWN)}$ and V_{BAT} is greater than V_{DD} . When V_{DD} recovers, switchover is deferred either until V_{DD} crosses V_{BAT} , or when V_{DD} rises above the threshold $(V_{(SWP)})$.

V _{DD} > V _{BAT}	V _{DD} > V _(SWN)	V _{OUT}
1	1	V_{DD}
1	0	V_{DD}
0	1	V_{DD}
0	0	V_{BAT}



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detailed description (continued)

manual switchover (MSWITCH)

While operating in the normal mode from VDD, the device can be manually forced to operate in the battery-backup mode by connecting MSWITCH to V_{DD}. The table below shows the different switchover modes.

	MSWITCH	Status
V	GND	V _{DD} mode
V _{DD} mode	V_{DD}	Switch to battery-backup mode
Dettem: beekun mede	GND	Battery-backup mode
Battery-backup mode	V_{DD}	Battery-backup mode

If the manual switchover feature is not used, MSWITCH must be connected to ground.

watchdog

In a microprocessor- or DSP-based system, it is not only important to supervise the supply voltage, it is also important to ensure the correct program execution. The task of a watchdog is to ensure that the program is not stalled in an indefinite loop. The microprocessor, microcontroller, or the DSP has to toggle the watchdog input within typically 0.8 s to avoid a time-out from occurring. Either a low-to-high or a high-to-low transition resets the internal watchdog timer. If the input is unconnected, the watchdog is disabled and is retriggered internally.

saving current while using the watchdog

The watchdog input is internally driven low during the first 7/8 of the watchdog time-out period, then momentarily pulses high, resetting the watchdog counter. For minimum watchdog input current (minimum overall power consumption), leave WDI low for the majority of the watchdog time-out period, pulsing it low-high-low once within 7/8 of the watchdog time-out period to reset the watchdog timer. If instead, WDI is externally driven high for the majority of the time-out period, a current of e.g. 5 V/40 k $\Omega \approx$ 125 μA can flow into WDI.

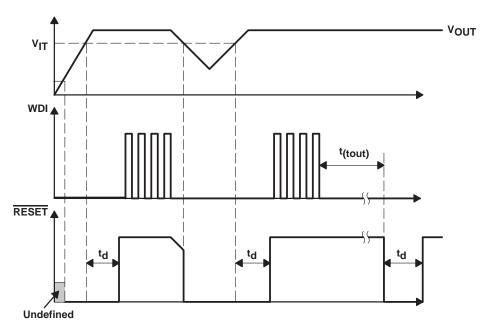


Figure 1. Watchdog Timing





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absolute maximum ratings over operating free-air temperature (unless otherwise noted)†

Supply voltage: V _{DD} (see Note1)	7 V
MR, WDI, and PFI pins (see Note 1)	$-0.3 \text{ V to } (V_{DD} + 0.3 \text{ V})$
Continuous output current at V _{OUT} : I _O	300 mA
All other pins, IO	±10 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	–40°C to 85°C
Storage temperature range, T _{stq}	–65°C to 150°C
Lead temperature soldering 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values are with respect to GND. For reliable operation the device must not be operated at 7 V for more than t = 1000h continuously.

DISSIPATION RATING TABLE

PACKAGE	T _A < 25°C	DERATING FACTOR	T _A = 70°C	T _A = 85°C
	POWER RATING	ABOVE T _A = 25°C	POWER RATING	POWER RATING
DGS	424 mW	3.4 mW/°C	271 mW	220 mW

recommended operating conditions at specified temperature range

		MIN	MAX	UNIT
Supply voltage, V _{DD}		1.65	5.5	V
Battery supply voltage, V _{BAT}		1.5	5.5	V
Input voltage, V _I		0	V _O + 0.3	V
High-level input voltage, VIH	0).7 x V _O		V
Low-level input voltage, all other pins, V _{IL}			0.3 x V _O	V
Continuous output current at VOUT, IO			200	mA
Input transition rise and fall rate at WDI, MSWITCH, $\Delta t/\Delta V$			100	ns/V
Slew rate at V _{DD} or V _{BAT}			34	mV/μs
Operating free-air temperature range, TA		-40	85	°C



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electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER			NDITIONS	MIN	TYP	MAX	UNIT
			V _{OUT} = 2 V,	I _{OH} = -400 μA	V _{OUT} – 0.2 V			
.,		RESET	V _{OUT} = 3.3 V V _{OUT} = 5 V,		V _{OUT} – 0.4 V			V
VOH	High-level output voltage		V _{OUT} = 1.8 V,	$I_{OH} = -20 \mu A$	V _{OUT} – 0.3 V			V
		PFO		$I_{OH} = -80 \mu A$ $I_{OH} = -120 \mu A$	V _{OUT} – 0.4 V			
		RESET	V _{OUT} = 2 V,	I _{OL} = 400 μA			0.2	
VOL	Low-level output voltage	PFO	V _{OUT} = 3.3 V, V _{OUT} = 5 V,				0.4	V
V _{res}	Power-up reset voltage (see Note 2)		V _{BAT} > 1.1 V V _{DD} > 1.4 V,				0.4	V
	Normal mode		$I_O = 5 \text{ mA},$	V _{DD} = 1.8 V	V _{DD} – 50 mV			
			$I_O = 75 \text{ mA},$	$V_{DD} = 3.3 \text{ V}$	V _{DD} – 150 mV			
Vout			$I_O = 150 \text{ mA},$	$V_{DD} = 5 V$	V _{DD} – 250 mV			V
	Battery-backup mode		$I_O = 4 \text{ mA},$	$V_{BAT} = 1.5 V$	V _{BAT} – 50 mV			
			$I_0 = 75 \text{ mA},$	V _{BAT} = 3.3 V	V _{BAT} – 150 mV			
F-I- ()	V _{DD} to V _{OUT} on-resistant	ce	$V_{DD} = 3.3 \text{ V}$			1	2	Ω
^r ds(on)	V _{BAT} to V _{OUT} on-resistar	ice	V _{BAT} = 3.3 V			1	2	32
VIT	Negative-going input threshold voltage (see Notes 3 and 4)	TPS3606x33			2.87	2.93	2.99	V
V _(PFI)	Power-fail input threshold voltage	PFI			1.13	1.15	1.17	
V _(SWN)	Battery switch threshold vonegative-going VOUT	oltage			V _{IT} + 1%	V _{IT} + 2%	V _{IT} + 3.2%	V

NOTES: 2. The lowest supply voltage at which $\overline{\text{RESET}}$ becomes active. $t_{f(VDD)} \ge 15 \,\mu\text{s/V}$.

- 3. To ensure best stability of the threshold voltage, a bypass capacitor (ceramic, 0.1 μF) should be placed near the supply terminal.
- 4. Voltage is sensed at VOUT
- For details on how to optimize current consumption when using WDI refer to section detailed description.





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electrical characteristics over recommended operating conditions (unless otherwise noted) (continued)

PARAMETER		TEST CONDITIONS	MIN TYP	MAX	UNIT	
			1.65 V < V _{IT} < 2.5 V	20		
		VIT	2.5 V < V _{IT} < 3.5 V	40		
1			3.5 V < V _{IT} < 5.5 V	50		
V _{hys}	Hysteresis	V _{PFI}		12		mV
´			1.65 V < V _(SWN) < 2.5 V	85		
		V(SWN)	2.5 V < V _(SWN) < 3.5 V	100		
			3.5 V < V _(SWN) < 5.5 V	110		
	TP-1 1 - 12 - 1 - 1 - 1 - 1	WDI	$WDI = V_{DD} = 5.5 V$		150	μА
ΙΗ	High-level input current	MR	$\overline{MR} = 0.7 \times V_{DD}, V_{DD} = 5 V$	-33	-76	
	La de alla de accesa	WDI	$WDI = 0 V$, $V_{DD} = 5 V$		-150	
^I IL	Low-level input current	MR	$\overline{MR} = 0 \text{ V}, \qquad V_{DD} = 5 \text{ V}$	-110	-255	
Ц	Input current	PFI, MSWITCH	$V_I < V_{DD}$	-25	25	nA
			PFO = 0 V, V _{DD} = 1.8 V		-0.3	
los	Short-circuit current	PFO	PFO = 0 V, V _{DD} = 3.3 V		-1.1	mA
			PFO = 0 V, V _{DD} = 5 V		-2.4	
I	\/ ounnly ourrent		V _{OUT} = V _{DD}		40	
lDD	V _{DD} supply current		V _{OUT} = V _{BAT}		8	μΑ
			$V_{OUT} = V_{DD}$	-0.1	0.1	
I(BAT)	I(BAT) VBAT supply current		V _{OUT} = V _{BAT}		40	μА
Ci	Input capacitance		V _I = 0 V to 5 V	5		pF

timing requirements at R_L = 1 M Ω , C_L = 50 pF, T_A = -40°C to 85°C

	PARAMETER	MIN	TYP	MAX	UNIT		
		V_{DD}	$V_{IH} = V_{IT} + 0.2 \text{ V}, V_{IL} = V_{IT} - 0.2 \text{ V}$	5			μs
t _w	Pulse width	MR	V V .00VV 00 V V 07 V	400			
		WDI	$V_{DD} > V_{IT} + 0.2 \text{ V}, V_{IL} = 0.3 \text{ x } V_{DD}, V_{IH} = 0.7 \text{ x } V_{DD}$	100			ns

switching characteristics at R_L= 1 M Ω , C_L = 50 pF, T_A = -40°C to 85°C

	PARAMETER		TEST C	MIN	TYP	MAX	UNIT	
t _d	Delay time	V _{DD} ≥ V _{IT} + 0.2 V, See timing diagram	$\overline{MR} \ge 0.7 \text{ x V}_{DD}$	60	100	140	ms	
t(tout)	Watchdog time-out		V _{DD} > V _{IT} + 0.2 V,	See timing diagram	0.48	0.8	1.12	S
	Propagation (delay) time, high-to-low-level output	V _{DD} to RESET	V _{IL} = V _{IT} - 0.2 V,	V _{IH} = V _{IT} + 0.2 V		2	5	μs
tou		PFI to PFO	$V_{IL} = V_{(PFI)} - 0.2 V,$	V _{IH} = V _(PFI) + 0.2 V		3	5	μs
[†] PHL		MR to RESET	$V_{DD} \ge V_{IT} + 0.2 \text{ V},$ $V_{IH} = 0.7 \text{ x } V_{DD}$	$V_{IL} = 0.3 \times V_{DD}$		0.1	1	μs
	Transition time	V _{DD} to V _{BAT}	V _{IL} = V _(BAT) - 0.2 V V _(BAT) < V _{IT}	V_{1} , $V_{1H} = V_{(BAT)} + 0.2 V_{1}$			3	μs





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TYPICAL CHARACTERISTICS

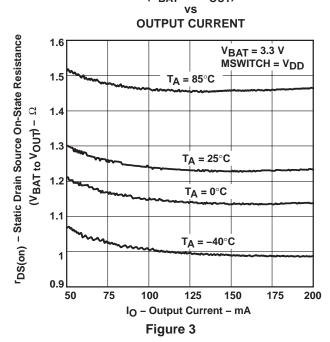
Table of Graphs

			FIGURE
	Static drain-source on-state resistance (V _{DD} to V _{OUT})	vs Output current	2
^r DS(on)	Static drain-source on-state resistance (VBAT to VOUT)	vs Output current	3
rDS(on) Star IDD Sul VIT Inp VOH Hig VOL Lov	0	vs Supply voltage	4
	Supply current	vs Battery supply	5
VIT	Input threshold voltage at RESET	vs Free-air temperature	6
.,	High-level output voltage at RESET	LEGIT IN THE STATE OF THE STATE	7, 8
VOH	High-level output voltage at PFO	vs High-level output current	9, 10
VOL	Low-level output voltage at RESET	vs Low-level output current	11, 12
	Minimum pulse duration at V _{DD}	vs Threshold voltage overdrive at V _{DD}	13
	Minimum pulse duration at PFI	vs Threshold voltage overdrive at PFI	14

STATIC DRAIN SOURCE ON-STATE RESISTANCE (V_{DD} TO V_{OUT})

vs **OUTPUT CURRENT** 1.5 ^rDS(on) - Static Drain Source On-State Resistance = 85°C 1.4 T_A 1.3 $\Omega - (TOD to Vout) - \Omega$ T_A = 25°C 1.2 T_A = 0°C 1.1 $T_A = -40^{\circ}C$ $V_{DD} = 3.3 \text{ V}$ 0.9 V_{BAT} = GND MSWITCH = GND 0.8 100 125 50 75 175 200 IO - Output Current - mA Figure 2

STATIC DRAIN SOURCE ON-STATE RESISTANCE (V_{BAT} TO V_{OUT})

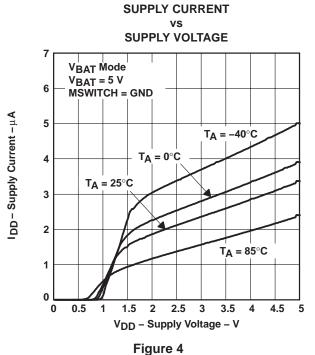




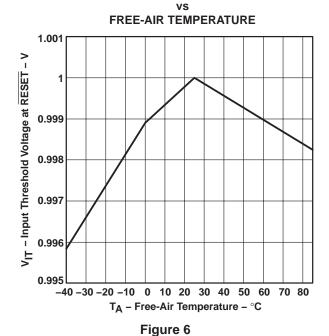


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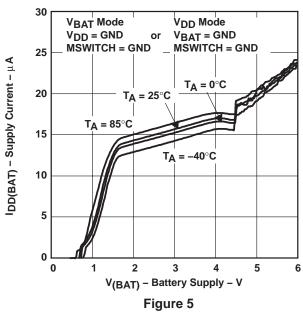
TYPICAL CHARACTERISTICS



INPUT THRESHOLD VOLTAGE AT RESET



SUPPLY CURRENT vs BATTERY SUPPLY



HIGH-LEVEL OUTPUT VOLTAGE AT RESET

HIGH-LEVEL OUTPUT CURRENT

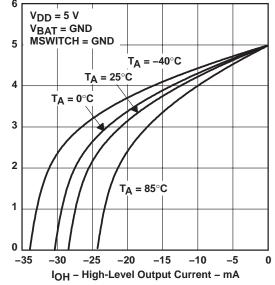


Figure 7

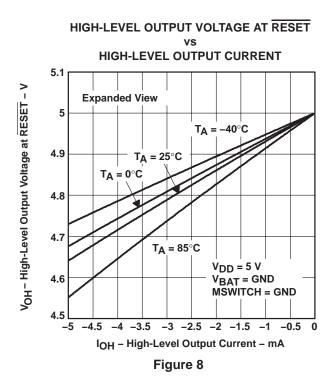


VOH - High-Level Output Voltage at RESET - V



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TYPICAL CHARACTERISTICS



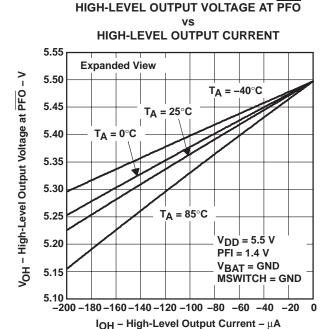
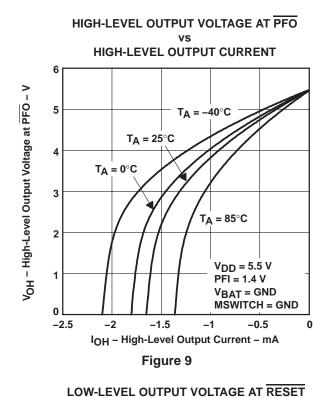
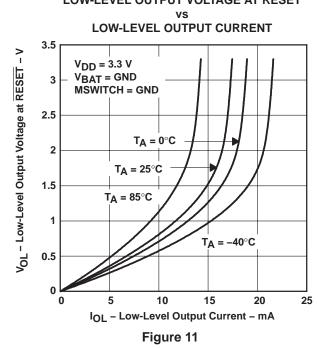


Figure 10









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TYPICAL CHARACTERISTICS

LOW-LEVEL OUTPUT VOLTAGE AT RESET LOW-LEVEL OUTPUT CURRENT 500 **Expanded View** VOL - Low-Level Output Voltage at RESET - mV T_A = 85°C V_{DD} = 3.3 V 400 $V_{BAT}^{-} = GND$ MSWITCH = GND T_A = 25°C 300 $T_A = 0^{\circ}C$ 200 T_A = -40°C 100 3 5 IOL - Low-Level Output Current - mA

Figure 12

MINIMUM PULSE DURATION AT V_{DD} THRESHOLD VOLTAGE OVERDRIVE AT VDD 10 9 Minimum Pulse Duration at V_{DD} – μ s 8 7 6 5 4 3 2 1 0 0.2 0.3 0.4 0.5 0.6 0.7 0.8 0.9 V_{T(O)} – Threshold Voltage Overdrive at V_{DD} – V

Figure 13

MINIMUM PULSE DURATION AT PFI vs

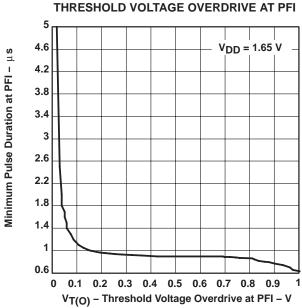


Figure 14





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PACKAGE OPTION ADDENDUM

29-Nov-2006

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TPS3606-33DGS	ACTIVE	MSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3606-33DGSG4	ACTIVE	MSOP	DGS	10	80	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3606-33DGSR	ACTIVE	MSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TPS3606-33DGSRG4	ACTIVE	MSOP	DGS	10	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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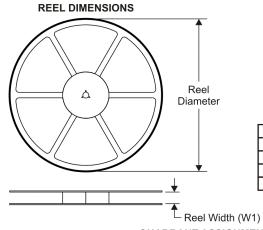
Datasheet of TPS3606-33DGS - IC BATT BACKUP SUPERVISR 10-MSOP Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com

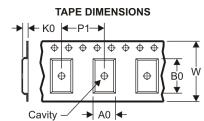


PACKAGE MATERIALS INFORMATION

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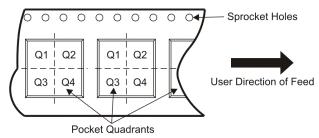
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

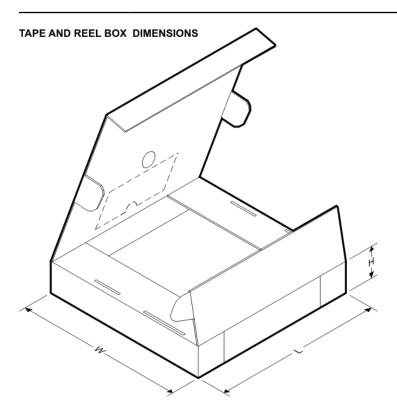
Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3606-33DGSR	MSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1

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*All dimensions are nominal

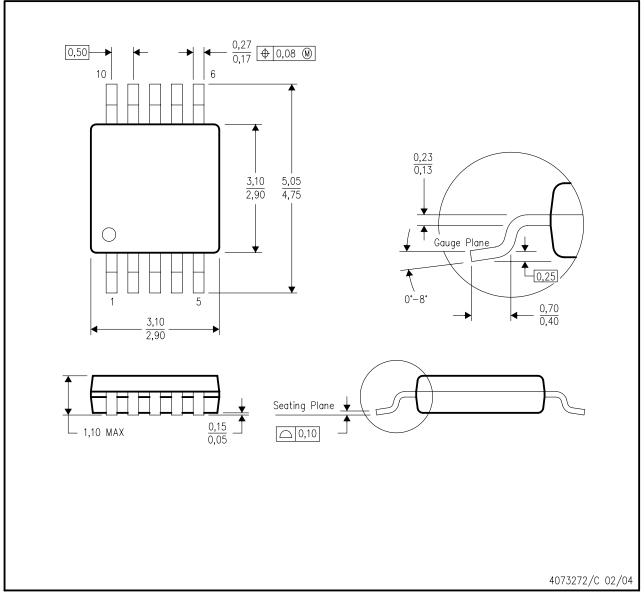
Device	Package Type	age Type Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3606-33DGSR	MSOP	DGS	10	2500	358.0	335.0	35.0



MECHANICAL DATA

DGS (S-PDSO-G10)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion.
- D. Falls within JEDEC MO-187 variation BA.





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